Vishay Semiconductors

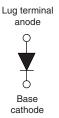
RoHS

COMPLIANT

High Performance Schottky Rectifier, 120 A



www.vishay.com



| HAL | F-PAK | (D-67) |
|-----|-------|--------|

| PRODUCT SUMMARY | | | | |
|--------------------|-----------------|--|--|--|
| I _{F(AV)} | 120 A | | | |
| V _R | 45 V | | | |
| Package | HALF-PAK (D-67) | | | |
| Circuit | Single diode | | | |

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- · Designed and qualified for industrial level
- UL approved file E222165
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-120NQ.. high current Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | |
|-----------------------------------|---|-----------------------------|----|--|--|--|--|
| SYMBOL | CHARACTERISTICS | CHARACTERISTICS VALUES UNIT | | | | | |
| I _{F(AV)} | Rectangular waveform | 120 | A | | | | |
| V _{RRM} | | 45 | V | | | | |
| I _{FSM} | t _p = 5 μs sine | 26 000 | A | | | | |
| V _F | 120 A _{pk} , T _J = 125 °C | 0.62 | V | | | | |
| ŢJ | Range | -55 to +150 | °C | | | | |

| VOLTAGE RATINGS | | | | | | |
|--------------------------------------|------------------|----------------|-------|--|--|--|
| PARAMETER | SYMBOL | VS-120NQ045PbF | UNITS | | | |
| Maximum DC reverse voltage | V _R | 45 | N/ | | | |
| Maximum working peak reverse voltage | V _{RWM} | – 45 V | | | | |

| ABSOLUTE MAXIMUM RATINGS | | | | | | |
|--|--------------------|---|---|--------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS | |
| Maximum average forward current See fig. 5 | I _{F(AV)} | 50 % duty cycle at T_{C} = 105 °C, rectangular waveform | | 120 | | |
| Maximum peak one cycle non-repetitive surge current | | 5 μs sine or 3 μs rect. pulse | Following any rated load condition and with rated | 26 000 | А | |
| See fig. 7 | IFSM | 10 ms sine or 6 ms rect. pulse | V _{RRM} applied | 1550 | | |
| Non-repetitive avalanche energy | E _{AS} | T _J = 25 °C, I _{AS} = 13 A, L = 1 mH | | 81 | mJ | |
| Repetitive avalanche current | I _{AR} | Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical | | 13 | А | |

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| ELECTRICAL SPECIFICATIONS | | | | | | |
|---------------------------------|--------------------------------|---|---------------------------------------|--------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS | |
| | | 120 A | T _ 25 °C | 0.63 | v | |
| Maximum forward voltage drop | V _{FM} ⁽¹⁾ | 240 A | — T _J = 25 °C | 0.86 | | |
| See fig. 1 | VFM (") | 120 A | | 0.62 | | |
| | | 240 A | $1_{\rm J} = 125$ C | 0.81 | | |
| Maximum reverse leakage current | . (1) | T _J = 25 °C | | 10 | mA | |
| See fig. 2 | I _{RM} ⁽¹⁾ | T _J = 125 °C | V _R = Rated V _R | 500 | | |
| Maximum junction capacitance | CT | $V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C | | 5200 | pF | |
| Typical series inductance | L _S | From top of terminal hole to mounting plane | | 7.0 | nH | |
| Maximum voltage rate of change | dV/dt | Rated V _R | | 10 000 | V/µs | |

Note

⁽¹⁾ Pulse width < 500 μ s

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | |
|--|---------------|-----------------------------------|--------------------------------------|------------|---------------------|
| PARAMETER | | SYMBOL TEST CONDITIONS | | VALUES | UNITS |
| Maximum junction and storage tempe | erature range | T _J , T _{Stg} | | -55 to 150 | °C |
| Maximum thermal resistance, junction to case | | R _{thJC} | DC operation See fig. 4 | 0.38 | °C/W |
| Typical thermal resistance, case to h | eatsink | R _{thCS} | Mounting surface, smooth and greased | 0.05 | |
| Approximate weight | | | | 30 | g |
| | | | | 1.06 | oz. |
| Mounting torque | minimum | | | 3 (26.5) | |
| Mounting torque | maximum | | Non-lubricated threads | 4 (35.4) | N · m (lbf · in) |
| Terminal terraua | minimum | | Non-lubricated trireaus | 3.4 (30) | |
| Terminal torque | maximum | | | 5 (44.2) | 1 |
| Case style | | | | HALF-PAP | K module |

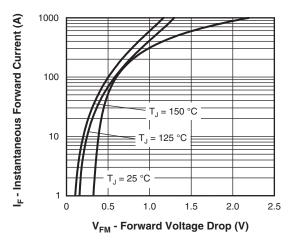
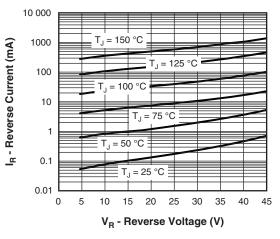
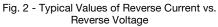


Fig. 1 - Maximum Forward Voltage Drop Characteristics





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VS-120NQ045PbF

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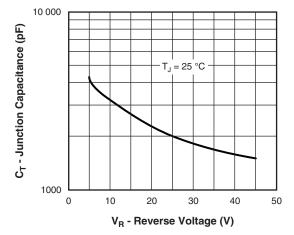


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

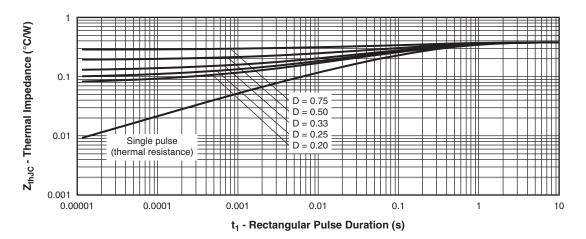
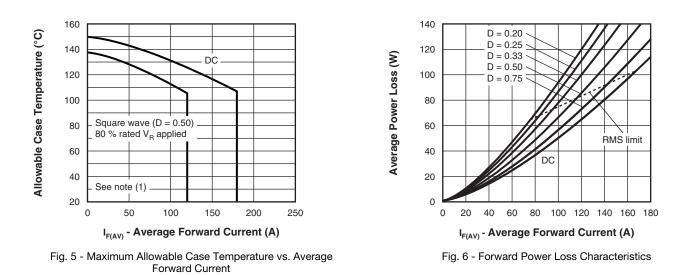


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



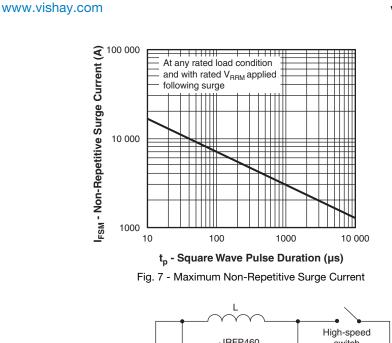
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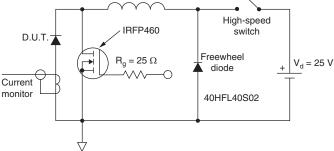
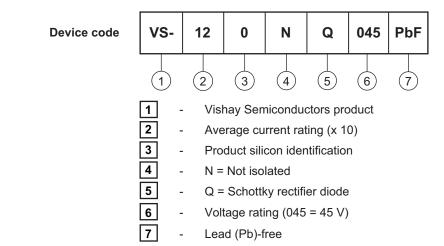


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC};$ $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D); I_R at V_{R1} = Rated V_R$

ORDERING INFORMATION TABLE



| LINKS TO RELATED DOCUMENTS | | | | | |
|---|--|--|--|--|--|
| Dimensions www.vishay.com/doc?95020 | | | | | |
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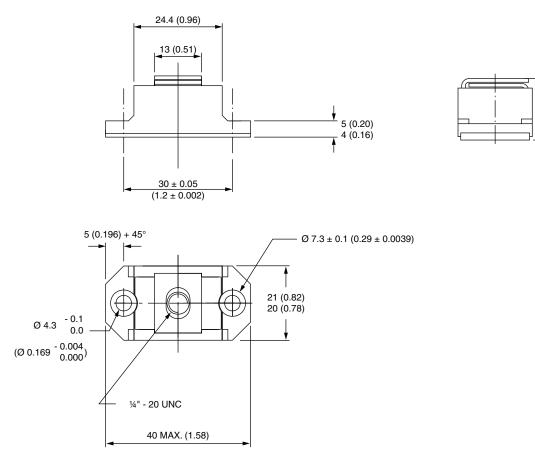
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17.5 (0.69) 16.5 (0.65)



DIMENSIONS in millimeters (inches)

SHAY





Vishay

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